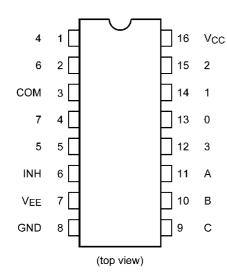
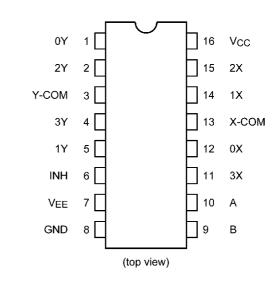
### 5. Pin Assignment



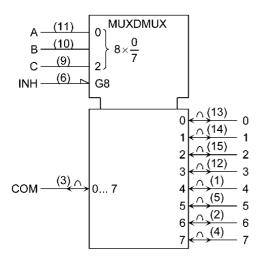


74HCT4052D

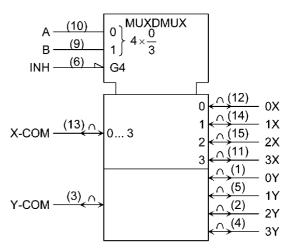


#### 6. IEC Logic Symbol

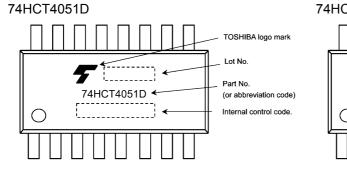


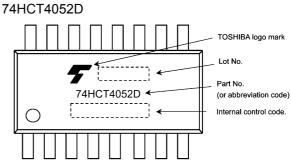


74HCT4052D



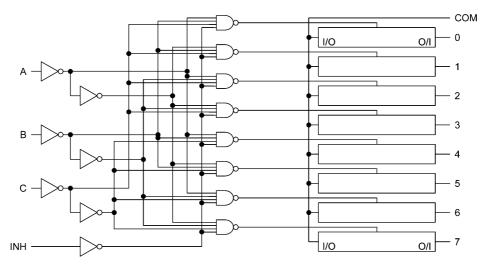
### 7. Marking



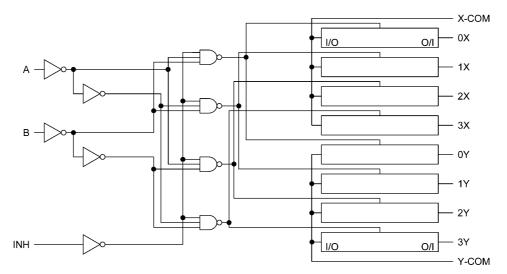


#### 8. System Diagram

#### 74HCT4051D



74HCT4052D



#### 9. Truth Table

Input Inhibit	Input C*	Input B	Input A	ON Channel 74HCT4051D	ON Channel 74HCT4052D
L	L	L	L	0	0X, 0Y
L	L	L	Н	1	1X, 1Y
L	L	Н	L	2	2X, 2Y
L	L	Н	Н	3	3X, 3Y
L	Н	L	L	4	_
L	Н	L	Н	5	_
L	Н	Н	L	6	_
L	Н	Н	Н	7	—
Н	Х	Х	Х	None	None

X: Don't care

\*: Except 74HCT4052D

#### 10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Supply voltage	V <sub>EE</sub>		-7.0 to 0	V
Supply voltage	V <sub>CC</sub> -V <sub>EE</sub>		-0.5 to 13.0	V
Input voltage	V <sub>IN</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Switch I/O voltage	V <sub>I/O</sub>		V <sub>EE</sub> - 0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		±20	mA
I/O diode current	I <sub>I/OK</sub>		±20	mA
Switch through current	Ι <sub>Τ</sub>		±25	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±50	mA
Power dissipation	PD	(Note 1)	500	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P<sub>D</sub> derates linearly with -8 mW/°C above 85 °C.

#### 11. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		4.5 to 5.5	V
Supply voltage	V <sub>EE</sub>		-6.0 to 0	V
Supply voltage	V <sub>CC</sub> -V <sub>EE</sub>		4.5 to 11.0	V
Input voltage	V <sub>IN</sub>		0 to V <sub>CC</sub>	V
Switch I/O voltage	V <sub>I/O</sub>		V <sub>EE</sub> to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	(Note 1)	-40 to 125	°C
Input rise and fall times	t <sub>r</sub> ,t <sub>f</sub>		0 to 50	μs

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V<sub>CC</sub> or GND.

Note 1: Operating Range spec of T<sub>opr</sub> = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

#### 12. Electrical Characteristics

### 12.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition	V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		4.5 to 5.5	2.0	_	_	V
Low-level input voltage	VIL	—	4.5 to 5.5	_	—	0.8	V	
ON-resistance	R <sub>ON</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	GND	4.5	_	180	240	Ω
		$V_{I/O} = V_{CC}$ to $V_{EE}$	-4.5	4.5	_	140	190	
		$I_{I/O} \le 2 \text{ mA}$	-5.5	5.5	_	135	180	
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{I/O} = V_{EE}$ $I_{I/O} \le 2 \text{ mA}$	GND	4.5	_	150	200	
			-4.5	4.5		135	170	
			-5.5	5.5	_	125	170	
			GND	4.5	_	95	130	
			-4.5	4.5		75	100	
			-5.5	5.5	_	70	100	
Difference of ON-resistance	$\Delta R_{ON}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$	GND	4.5	_	10	30	Ω
between switches		$V_{I/O} = V_{CC}$ to $V_{EE}$ $I_{I/O} \le 2 \text{ mA}$	-4.5	4.5	_	5	12	
		$1/0 \ge 2 11/4$	-5.5	5.5	_	5	11	
Input/Output leakage current	I <sub>OFF</sub>	$V_{OS} = V_{CC}$ or GND	GND	5.5	_	—	±0.06	μA
(Switch OFF)		$V_{IS} = GND \text{ or } V_{CC}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$	-5.5	5.5	_	—	±0.1	
Input/Output leakage current	I <sub>I/O</sub>	V <sub>OS</sub> = V <sub>CC</sub> or GND	GND	5.5	_	—	±0.06	μA
(Switch ON)		$V_{IN} = V_{IH} \text{ or } V_{IL}$	-5.5	5.5	_	_	±0.1	
Control input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	GND	5.5	_	—	±0.1	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	GND	5.5	_	_	4.0	μA
			-5.5	5.5		_	8.0	
		Per input: $V_{IN}$ = 0.5 V or 2.4 V Other input: V <sub>CC</sub> or GND	GND	5.5	_	—	2.0	mA

### 12.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition	V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		4.5 to 5.5	2.0	_	V
Low-level input voltage	VIL	—		4.5 to 5.5	_	0.8	V
ON-resistance	R <sub>ON</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	GND	4.5	_	300	Ω
		$V_{I/O} = V_{CC}$ to $V_{EE}$ $I_{I/O} \le 2 \text{ mA}$	-4.5	4.5	_	240	
		II/0 ≤ 2 IIIA	-5.5	5.5	_	225	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	GND	4.5	_	250	]
		$V_{I/O} = V_{EE}$ $I_{I/O} \le 2 \text{ mA}$	-4.5	4.5	_	215	]
		II/0 ≤ 2 IIIA	-5.5	5.5	_	215	1
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	GND	4.5	_	165	1
		$V_{I/O} = V_{CC}$ $I_{I/O} \le 2 \text{ mA}$	-4.5	4.5	_	125	]
		II/0 ≤ 2 IIIA	-5.5	5.5	_	125	1
Difference of ON-resistance	$\Delta R_{ON}$	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	GND	4.5	_	35	Ω
between switches		$V_{I/O} = V_{CC}$ to $V_{EE}$ $I_{I/O} \le 2 \text{ mA}$	-4.5	4.5	_	15	
		II/0 ≤ 2 IIIA	-5.5	5.5	_	14	1
Input/Output leakage current (Switch OFF)	I <sub>OFF</sub>	V <sub>OS</sub> = V <sub>CC</sub> or GND V <sub>IS</sub> = GND or V <sub>CC</sub>	GND	5.5		±0.6	μΑ
(Switch OFF)		$V_{IN} = V_{IH} \text{ or } V_{IL}$	-5.5	5.5	_	±1.0	
Input/Output leakage current	I <sub>I/O</sub>	V <sub>OS</sub> = V <sub>CC</sub> or GND	GND	5.5	_	±0.6	μΑ
(Switch ON)		$V_{IN} = V_{IH} \text{ or } V_{IL}$	-5.5	5.5	_	±1.0	1
Control input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	GND	5.5	_	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	GND	5.5	_	40.0	μΑ
			-5.5	5.5	_	80.0	
		Per input: V <sub>IN</sub> = 0.5 V or 2.4 V Other input: V <sub>CC</sub> or GND	GND	5.5	_	2.9	mA

Characteristics	Symbol	Test Condition	V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Min	Мах	Unit
High-level input voltage	V <sub>IH</sub>	—		4.5 to 5.5	2.0	—	V
Low-level input voltage	V <sub>IL</sub>	—	4.5 to 5.5		0.8	V	
ON-resistance	R <sub>ON</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	GND	4.5		340	Ω
		$V_{I/O} = V_{CC}$ to $V_{EE}$ $I_{I/O} \le 2 \text{ mA}$	-4.5	4.5		275	
			-5.5	5.5		255	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	GND	4.5	_	285	]
		$V_{I/O} = V_{EE}$	-4.5	4.5	_	245	
		$I_{I/O} \le 2 \text{ mA}$	-5.5	5.5	_	245	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	GND	4.5	_	190	
		$V_{I/O} = V_{CC}$ $I_{I/O} \le 2 \text{ mA}$	-4.5	4.5	_	145	
		II/0 ≤ 2 IIIA	-5.5	5.5	_	145	
Difference of ON-resistance	$\Delta R_{ON}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{I/O} = V_{CC} \text{ to } V_{EE}$ $I_{I/O} \le 2 \text{ mA}$	GND	4.5	_	35	Ω
between switches			-4.5	4.5	_	15	
			-5.5	5.5	_	14	
Input/Output leakage current	I <sub>OFF</sub>	$V_{OS} = V_{CC}$ or GND	GND	5.5		±3.0	μΑ
(Switch OFF)		$V_{IS} = GND \text{ or } V_{CC}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$	-5.5	5.5	_	±5.0	
Input/Output leakage current	I <sub>I/O</sub>	V <sub>OS</sub> = V <sub>CC</sub> or GND	GND	5.5	_	±3.0	μA
(Switch ON)		$V_{IN} = V_{IH} \text{ or } V_{IL}$	-5.5	5.5	_	±5.0	
Control input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	GND	5.5	_	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	GND	5.5	_	80.0	μA
			-5.5	5.5	_	160.0	]
		Per input: V <sub>IN</sub> = 0.5 V or 2.4 V Other input: V <sub>CC</sub> or GND	GND	5.5	_	2.9	mA

#### 12.3. DC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

Note: Operating Range spec of T<sub>opr</sub> = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

#### 12.4. AC Characteristics (Unless otherwise specified, $C_L = 50 \text{ pF}$ , $T_a = 25 \text{ }^\circ\text{C}$ , Input: $t_r = t_f = 6 \text{ ns}$ )

-									
Characteristics	Part Number	Symbol	Test Condition	$V_{EE}\left(V\right)$	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
Phase difference		Φι/Ο	—	GND	4.5	_	7	12	ns
between input to output				GND	5.5	_	6	10	]
				-4.5	4.5	_	5	_	]
Output enable time	74HCT4051D	t <sub>PZL</sub> ,t <sub>PZH</sub>	$R_L = 1 k\Omega$	GND	4.5		30	45	ns
			Figure 1	GND	5.5		26	35	
				-4.5	4.5		25	35	
	74HCT4052D		$R_L = 1 k\Omega$	GND	4.5	_	30	45	ns
			Figure 1	GND	5.5	_	26	35	
				-4.5	4.5	_	25	35	1
Output disable time	74HCT4051D	t <sub>PLZ</sub> ,t <sub>PHZ</sub>	R <sub>L</sub> = 1 kΩ	GND	4.5		22	30	ns
			Figure 1	GND	5.5	_	21	28	]
				-4.5	4.5		21	28	1
	74HCT4052D		R <sub>L</sub> = 1 kΩ Figure 1	GND	4.5	_	22	30	ns
				GND	5.5	_	21	28	
				-4.5	4.5	_	21	28	]
Control input capacitance		C <sub>IN</sub>	—	_	—	_	5	10	pF
Common terminal	74HCT4051D	C <sub>IS</sub>	Figure 2	-5.0	5.0	_	36	70	pF
capacitance	74HCT4052D					_	19	40	]
Switch terminal	74HCT4051D	C <sub>OS</sub>	Figure 2	-5.0	5.0		7	15	pF
capacitance	74HCT4052D						7	15	
Feedthrough	74HCT4051D	C <sub>IOS</sub>	Figure 2	-5.0	5.0		0.75	2	pF
capacitance	74HCT4052D					_	0.75	2	1
Power dissipation	74HCT4051D	C <sub>PD</sub>	Figure 2	GND	5.0		11	_	pF
capacitance	74HCT4052D		(Note 1)				19	_	1

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$ 



# 12.5. AC Characteristics (Unless otherwise specified, $C_L$ = 50 pF, $T_a$ = -40 to 85 °C, Input: $t_r$ = $t_f$ = 6 ns)

Characteristics	Part Number	Symbol	Test Condition	$V_{\text{EE}}$ (V)	V <sub>CC</sub> (V)	Min	Max	Unit
Phase difference between		Ψι/Ο	—	GND	4.5	_	15	ns
input to output				GND	5.5	_	13	
				-4.5	4.5	_	_	
Output enable time	74HCT4051D	t <sub>PZL</sub> ,t <sub>PZH</sub>	$R_L = 1 k\Omega$	GND	4.5	_	55	ns
			Figure 1	GND	5.5	_	42	
				-4.5	4.5	_	41	
	74HCT4052D		$R_L = 1 k\Omega$	GND	4.5	—	55	ns
			Figure 1	GND	5.5	_	42	
				-4.5	4.5	—	41	
Output disable time	74HCT4051D	t <sub>PLZ</sub> ,t <sub>PHZ</sub>	$R_L = 1 k\Omega$	GND	4.5	—	37	ns
			Figure 1	GND	5.5	—	34	
				-4.5	4.5	—	34	
	74HCT4052D		R <sub>L</sub> = 1 kΩ	GND	4.5	_	37	ns
			Figure 1	GND	5.5	_	34	
				-4.5	4.5	_	34	
Control input capacitance		C <sub>IN</sub>	—	—	—	_	10	pF
Common terminal	74HCT4051D	C <sub>IS</sub>	Figure 2	-5.0	5.0	_	70	pF
capacitance	74HCT4052D					—	40	
Switch terminal capacitance	74HCT4051D	C <sub>OS</sub>	Figure 2	-5.0	5.0	_	15	pF
	74HCT4052D					_	15	
Feedthrough capacitance	74HCT4051D	C <sub>IOS</sub>	Figure 2	-5.0	5.0	_	2	pF
	74HCT4052D					_	2	



#### 12.6. AC Characteristics (Note) (Unless otherwise specified, CL = 50 pF, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Part Number	Symbol	Test Condition	V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Min	Max	Unit
Phase difference between		Φι/Ο	—	GND	4.5	—	17	ns
input to output				GND	5.0	_	15	
				-4.5	4.5	_	_	1
Output enable time	74HCT4051D	t <sub>PZL</sub> ,t <sub>PZH</sub>	R <sub>L</sub> = 1 kΩ	GND	4.5	_	62	ns
			Figure 1	GND	5.0	—	47	
				-4.5	4.5	_	45	
	74HCT4052D		R <sub>L</sub> = 1 kΩ	GND	4.5	—	62	ns
			Figure 1	GND	5.0	—	47	
				-4.5	4.5	_	45	]
Output disable time	74HCT4051D	t <sub>PLZ</sub> ,t <sub>PHZ</sub>	R <sub>L</sub> = 1 kΩ Figure 1 R <sub>L</sub> = 1 kΩ Figure 1	GND	4.5	—	42	ns
	74HCT4052D			GND	5.0	—	38	
				-4.5	4.5	_	38	
				GND	4.5	—	42	ns
				GND	5.0	—	38	
				-4.5	4.5	_	38	
Control input capacitance		C <sub>IN</sub>	—	—	—	—	10	pF
Common terminal	74HCT4051D	C <sub>IS</sub>	Figure 2	-5.0	5.0	_	70	pF
capacitance	74HCT4052D					_	40	]
Switch terminal capacitance	74HCT4051D	C <sub>OS</sub>	Figure 2	-5.0	5.0	_	15	pF
	74HCT4052D					_	15	
Feedthrough capacitance	74HCT4051D	C <sub>IOS</sub>	Figure 2	-5.0	5.0	_	2	pF
	74HCT4052D					_	2	1

Note: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

#### 12.7. Analog Switch Characteristics ( $T_a = 25 \ ^{\circ}C$ ) (Note)

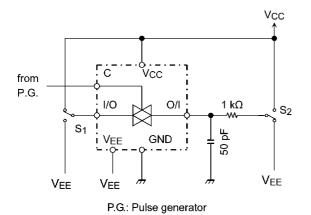
Characteristics	Part Number	Symbol	Test Condition		V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Тур.	Unit
Sine Wave Distortion		THD	$R_L$ = 10 k $\Omega$ , $C_L$ = 50 pF	$V_{IN} = 8.0 V_{p-p}$	-4.5	4.5	0.020	%
			f <sub>IN</sub> = 1 kHz	V <sub>IN</sub> = 11.0 V <sub>p-p</sub>	-5.5	5.5	0.019	
Maximum frequency		f <sub>MAX(I/O)</sub>		(Note 1)	-4.5	4.5	190	MHz
response	74HCT4051D		0 dBm at V <sub>OS</sub> Increase f <sub>IN</sub> frequency until	(Note 2)			70	
	74HCT4052D		dB meter reads -3 dB				110	
			f <sub>IN</sub> = 1 MHz sine wave	(Note 1)	-5.5	5.5	200	
	74HCT4051D			(Note 2)			80	
	74HCT4052D		<b>3</b>				135	
Feed through attenuation (switch OFF)		FTH	$V_{IN}$ is centered at ( $V_{CC}/2$ ). Adjust input for 0 dBm.		-4.5	4.5	-50	dB
			$R_L$ = 600 $\Omega$ , $C_L$ = 50 pF, f <sub>IN</sub> = 1 MHz, sine wave Figure 4		-5.5	5.5	-50	
Crosstalk (control input to signal output)		X <sub>talk</sub>	$R_L = 600 \Omega$ , $C_L = 50 pF$ , f <sub>IN</sub> = 1 MHz,		-4.5	4.5	140	mV
			square wave (t <sub>r</sub> = t <sub>f</sub> = 6 ns) Figure 5		-5.5	5.5	180	
Crosstalk (between any switches)		X <sub>talk</sub>	Adjust $V_{IN}$ to obtain 0 dBm at input.		-4.5	4.5	-50	dB
			$R_L$ = 600 $\Omega$ , $C_L$ = 50 pF, f <sub>IN</sub> = 1 MHz, sine wave Figure 6		-5.5	5.5	-50	
			$R_L$ = 50 Ω, $C_L$ = 15 pF, $f_{IN}$ = 100 KHz, $V_{SWITCH}$ = 1 $V_{RMS}$ Figure 6		-4.5	4.5	-90	dB

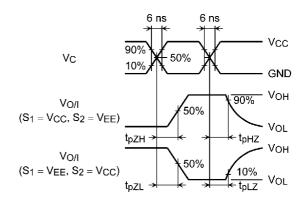
Note: These characteristics are determined by design of devices.

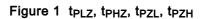
Note 1: Input COMMON terminal, and measured at SWITCH terminal.

Note 2: Input SWITCH terminal, and measured at COMMON terminal.

#### 13. AC Test Circuit







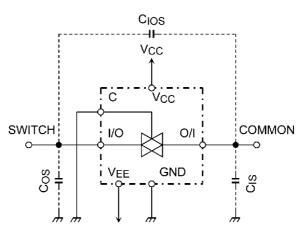


Figure 2 CIOS, CIS, COS

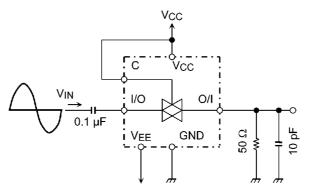


Figure 3 Frequency Response

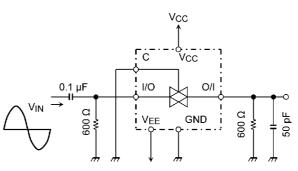
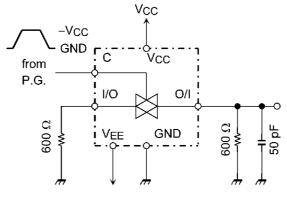
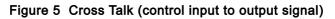


Figure 4 Feedthrough Attenuation



P.G.: Pulse generator



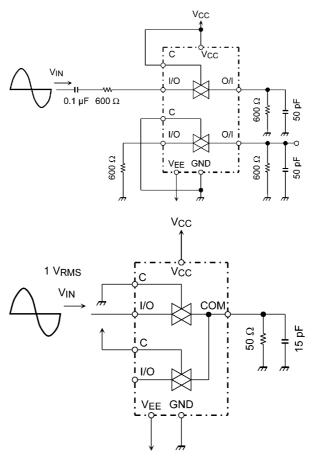


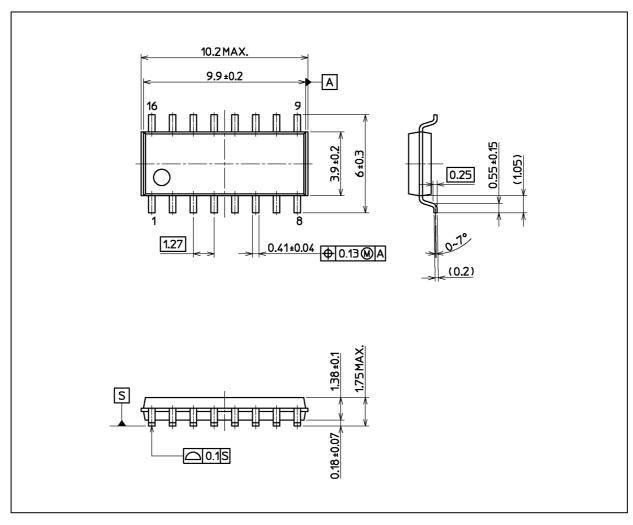
Figure 6 Cross Talk (between any two switches)



### 74HCT4051D,74HCT4052D

#### **Package Dimensions**

Unit: mm



Weight: 0.15 g (typ.)

Package Name(s)

Nickname: SOIC16

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